Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-179-0411

Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
400.00 milliamperes forward current, total rms nanoamperes
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Test Data Document:
86360-741c7640-04 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

A110a0